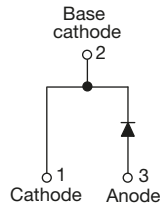


High Performance Schottky Rectifier, 10 A


2L TO-220AC


FEATURES

- 150 °C T_J operation
- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	10 A
V_R	35 V, 45 V
V_F at I_F	0.57 V
I_{RM} max.	15 mA at 125 °C
T_J max.	150 °C
E_{AS}	8 mJ
Package	2L TO-220AC
Circuit configuration	Single

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	10	A
I_{FRM}	$T_C = 135$ °C	20	
V_{RRM}		35/45	V
I_{FSM}	$t_p = 5$ μ s sine	1060	A
V_F	10 A_{pk} , $T_J = 125$ °C	0.57	V
T_J	Range	-65 to +150	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-MBR1035-M3	VS-MBR1045-M3	UNITS
Maximum DC reverse voltage	V_R	35	45	V
Maximum working peak reverse voltage	V_{RWM}			

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 135$ °C, rated V_R	10	A
Peak repetitive forward current	I_{FRM}	Rated V_R , square wave, 20 kHz, $T_C = 135$ °C	20	
Non-repetitive peak surge current	I_{FSM}	5 μ s sine or 3 μ s rect. pulse	1060	A
		Surge applied at rated load conditions halfwave, single phase, 60 Hz	150	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25$ °C, $I_{AS} = 2$ A, $L = 4$ mH	8	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical	2	A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}^{(1)}$	20 A	$T_J = 25\text{ }^\circ\text{C}$	0.84	V
		10 A	$T_J = 125\text{ }^\circ\text{C}$	0.57	
		20 A		0.72	
Maximum instantaneous reverse current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	Rated DC voltage	0.1	mA
		$T_J = 125\text{ }^\circ\text{C}$		15	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$		0.354	V
Forward slope resistance	r_t			17.6	m Ω
Maximum junction capacitance	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		600	pF
Typical series inductance	L_S	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s

Note(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction temperature range	T_J			-65 to +150	$^\circ\text{C}$
Maximum storage temperature range	T_{Stg}			-65 to +175	
Maximum thermal resistance, junction to case	R_{thJC}	DC operation		2.0	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased		0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device		Case style 2L TO-220AC		MBR1035	
				MBR1045	

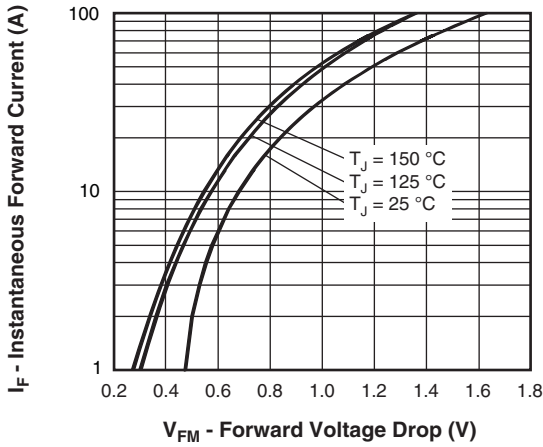


Fig. 1 - Maximum Forward Voltage Drop Characteristics

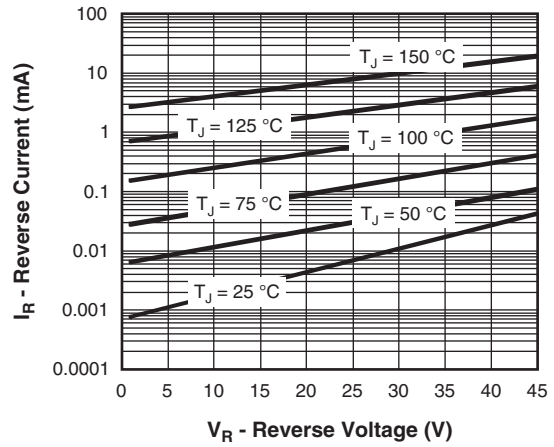


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

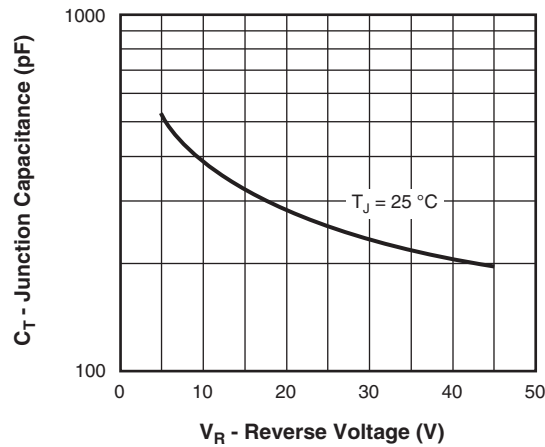


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

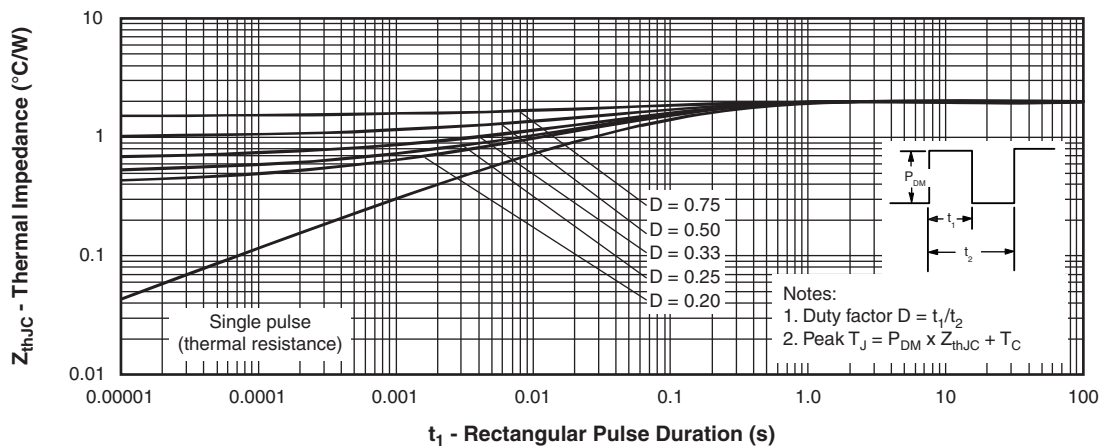


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

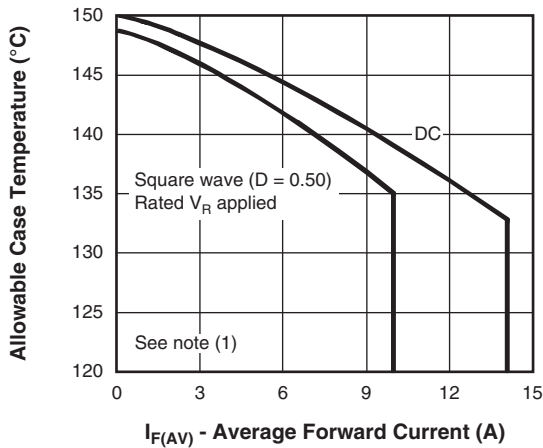


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

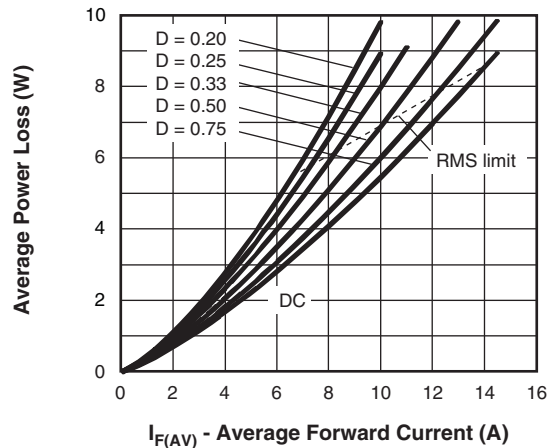


Fig. 6 - Forward Power Loss Characteristics

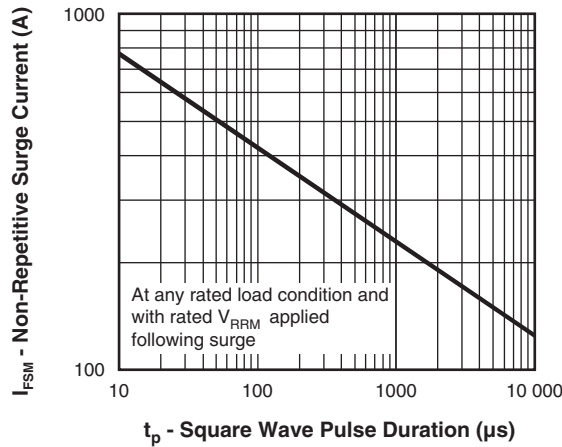


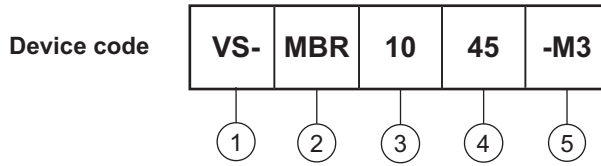
Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
 - 2** - Schottky MBR series
 - 3** - Current rating (10 = 10 A)
 - 4** - Voltage ratings 35 = 35 V
45 = 45 V
 - 5** - Environmental digit
- M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-MBR1035-M3	50	1000	Antistatic plastic tube
VS-MBR1045-M3	50	1000	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96156
Part marking information	www.vishay.com/doc?95391
SPIICE model	www.vishay.com/doc?95293



2L TO-220AC

DIMENSIONS in millimeters and inches



Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183		D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055		E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115		E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040		e	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4	e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068		H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4	L	13.52	14.02	0.532	0.552	
c	0.36	0.61	0.014	0.024		L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4	∅ P	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3	Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355							

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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